# **NPN Silicon Planar Power Transistor**

160Vсво, 10А Іс, ТО-3

# multicomp PRO

# RoHS Compliant



# Description

This is High-power industrial transistor NPN silicon power transistor designed for applications in industrial and commercial equipment including high fidelity audio amplifiers, series and shunt regulators and power switches

## Features

- 1. Higher safe operating area at VCE >40V
- 2. Low saturation voltages
- 3. High power dissipation capability

## **Applications:**

For high power audio, series pass power supplies, disk-head positioners and other linear application. These devices can also be used in power switching circuits such as converters or inverters

#### Absolute Maximum Ratings (TA = 25 °C)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	Vсво	160	
Collector-Emitter Voltage	Vceo	140	V DC
Emitter-Base Voltage	Vebo	7	
Collector Current-continuous	lc	10	
Collector Current-Peak	Ісм	15	A
Base Current	Ів	7	
Total Power Dissipation @TC= 25°C		117	W
Total Power Dissipation Derate above @TC= 25°C	PD	0.67	W/ °C
Operating and Storage Junction Temperature Range	Тј,Тѕтс	-65 to +200	°C

## **Thermal Characteristics**

Parameter	Symbol	Value	Unit
Thermal Resistance Junction to Case	$R_{_{ extsf{ heta}c}}$	1.17	°C/W

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# Electrical Characteristics at TA = 25 °C unless otherwise specified

Devenueter	Cumb al	Test Conditions	Value		Unit	
Parameter	Symbol	Test Conditions	Min.	Max.	Unit	
Off Characteristics						
Collector-Emitter Sustaining Voltage	Vceo(sus)	Ic= 200mA, Iв=0	140	-	V DC	
Collector Cut-off Current	ICEO	Vce=140V, Ib=0	-	200		
		V <sub>CE</sub> =140 V DC, V <sub>BE</sub> (off)=1.5 V DC	-	5		
Collector Cut-off Current	ICEX	V <sub>CE</sub> =140V DC, mA V <sub>BE (off)</sub> =1.5V DC, T <sub>C</sub> =150°C	-	30	mA	
Emitter Cut-off Current	Іево	VEB = 7V DC, Ic = 0	-	5		
On Characteristics Note3.						
DO Ourrent Onlin	b	IC= 3A DC, VCE= 4V DC)	2	70		
	TIFE	Ic=10A DC, VcE=4V DC	7.5	-		
Collector-Emitter Saturation Voltage	VCE(SAT)	Ic = 10A DC, Iв = 2A DC	-	5		
Base-Emitter On Voltage	VBE(SAT)	Ic=10A DC, VcE=4V DC	-	5.7		
Dynamic Characteristics						
Current-Gain - Bandwidth Product (Note 4)	f⊤	Ic=2A DC, Vce=4V DC, ftest = 40kHz	80	-	kHz	
Small-Signal Current Gain	hfe	Ic=2A DC, Vce=4V DC, f=1kHz	12	72		

#### Note:

(3) Pulse Test : Pulse Width = 300µs, Duty Cycle ≤2%

(4) fT = | hfe | • ftest



Din	Min	Max
Α	_	40
В	_	25
С	6.35	11.43
D	0.70	1.09
E	_	3.8
F	29.90	30.40

Din	Min	Max
G	10.67	11.18
Н	5.21	5.72
J	16.64	17.15
К	7.92	_
L	_	26.68
М	3.84	4.09

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## **Recommended Product Storage Environment for Diode and Transistors**

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by.

Temperature 5°C to 30°C

- · Humidity between 40%RH to 70%RH
- · Air should be clean.
- · Avoid harmful gas or dust
- · Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- · Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- Avoid rapid change of temperature.
- · Avoid condensation.
- · Mechanical stress such as vibration and impact shall be avoided.
- · The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

### **Shelf Life of Products**

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years, the products shall be subjected to quality check as per COIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in COIL original packing.

#### Floor Life of Products and MSL Level

When the products are opened from the original packing, the floor life will start. For this the following JEDEC table may be referred:

JEDEC MSL Level			
Level	Time	Condition	
1	Unlimited	≤30°C / 85% RH	
2	1 Year	≤30°C / 60% RH	
2a	4 Weeks	≤30°C / 60% RH	
3	168 Hours	≤30 °C / 60% RH	
4	72 Hours	≤30°C / 60% RH	
5	48 Hours	≤30°C / 60% RH	
Sa	24 Hours	≤30°C / 60% RH	
6	Time on Label (TOL)	≤30°C / 60% RH	

## Part Number Table

Description	Part Number
NPN Silicon Planar Power Transistor, 160 VCBO, 10A Ic, TO-3	2N3442

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